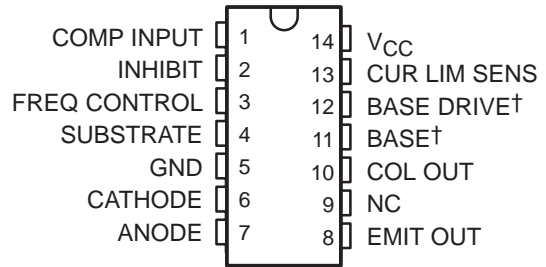


TL497A SWITCHING VOLTAGE REGULATORS

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- High Efficiency . . . 60% or Greater
- Output Current . . . 500 mA
- Input Current Limit Protection
- TTL-Compatible Inhibit
- Adjustable Output Voltage
- Input Regulation . . . 0.2% Typ
- Output Regulation . . . 0.4% Typ
- Soft Start-Up Capability

D, N, OR PW PACKAGE
(TOP VIEW)



description

The TL497A incorporates all the active functions required in the construction of switching voltage regulators. It can also be used as the control element to drive external components for high-power-output applications. The TL497A was designed for ease of use in step-up, step-down, or voltage-inversion applications requiring high efficiency.

The TL497A is a fixed-on-time variable-frequency switching-voltage-regulator control circuit. The switch-on time is programmed by a single external capacitor connected between FREQ CONTROL and GND. This capacitor, C_T , is charged by an internal constant-current generator to a predetermined threshold. The charging current and the threshold vary proportionally with V_{CC} . Thus, the switch-on time remains constant over the specified range of input voltage (4.5 V to 12 V). Typical on times for various values of C_T are as follows:

TIMING CAPACITOR, C_T (pF)	200	250	350	400	500	750	1000	1500	2000
ON TIME (μ s)	19	22	26	32	44	56	80	120	180

The output voltage is controlled by an external resistor ladder network (R_1 and R_2 in Figures 1, 2, and 3) that provides a feedback voltage to the comparator input. This feedback voltage is compared to the reference voltage of 1.2 V (relative to SUBSTRATE) by the high-gain comparator. When the output voltage decays below the value required to maintain 1.2 V at the comparator input, the comparator enables the oscillator circuit, which charges and discharges C_T as described above. The internal pass transistor is driven on during the charging of C_T . The internal transistor can be used directly for switching currents up to 500 mA. Its collector and emitter are uncommitted, and it is current driven to allow operation from the positive supply voltage or ground. An internal Schottky diode matched to the current characteristics of the internal transistor also is available for blocking or commutating purposes. The TL497A also has on-chip current-limit circuitry that senses the peak currents in the switching regulator and protects the inductor against saturation and the pass transistor against overstress. The current limit is adjustable and is programmed by a single sense resistor, R_{CL} , connected between V_{CC} and CUR LIM SENS. The current-limit circuitry is activated when 0.7 V is developed across R_{CL} . External gating is provided by the INHIBIT input. When the INHIBIT input is high, the output is turned off.

Simplicity of design is a primary feature of the TL497A. With only six external components (three resistors, two capacitors, and one inductor), the TL497A operates in numerous voltage-conversion applications (step-up, step-down, invert) with as much as 85% of the source power delivered to the load. The TL497A replaces the TL497 in all applications.

The TL497AC is characterized for operation from 0°C to 70°C. The TL497AI is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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TL497A

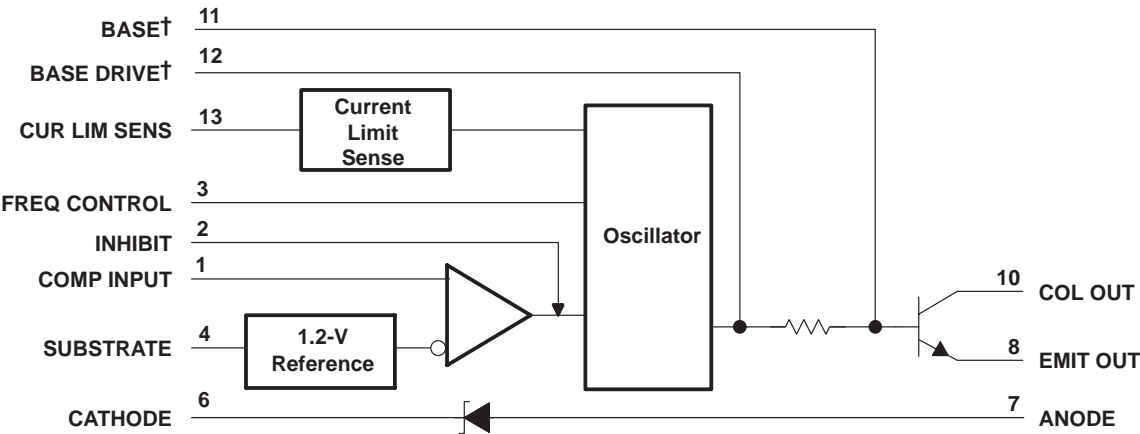
SWITCHING VOLTAGE REGULATORS

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AVAILABLE OPTIONS				
T _A	PACKAGED DEVICES			CHIP FORM (Y)
	SMALL-OUTLINE (D)	PLASTIC DIP (N)	SHRINK SMALL-OUTLINE (PW)	
0°C to 70°C	TL497ACD	TL497ACN	TL497ACPW	TL497AY
–40°C to 85°C	TL497AID	TL497AIN	—	—

The D and PW packages are only taped and reeled. Add the suffix R to the device type (e.g., TL497ACPWR). Chip forms are tested at 25°C.

functional block diagram



† BASE and BASE DRIVE are used for device testing only. They normally are not used in circuit applications of the device.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1)	15 V
Output voltage, V_O	35 V
Input voltage, V_I (COMP INPUT)	5 V
Input voltage, V_I (INHIBIT)	5 V
Diode reverse voltage	35 V
Power switch current	750 mA
Diode forward current	750 mA
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D package	86°C/W
N package	101°C/W
PW package	113°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	260°C
Storage temperature range, T_{stg}	–65°C to 150°C

†Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values except diode voltages are with respect to network ground terminal.
 2. Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{CC}		4.5	12	V
High-level input voltage, V_{IH}	INHIBIT pin	2.5		V
Low-level input voltage, V_{IL}	INHIBIT pin		0.8	V
Output voltage	Step-up configuration (see Figure 1)	$V_I + 2$	30	V
	Step-down configuration (see Figure 2)	V_{ref}	$V_I - 1$	
	Inverting regulator (see Figure 3)	$-V_{ref}$	–25	
Power switch current			500	mA
Diode forward current			500	mA
Operating free-air temperature range, T_A	TL497AC	0	70	°C
	TL497AI	–40	85	

TL497A

SWITCHING VOLTAGE REGULATORS

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electrical characteristics over recommended operating conditions, $V_{CC} = 6\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TL497AC			TL497AI			UNIT
			MIN	TYP‡	MAX	MIN	TYP‡	MAX	
High-level input current, INHIBIT	$V_{I(I)} = 5\text{ V}$	Full range	0.8	1.5		0.8	1.5		mA
Low-level input current, INHIBIT	$V_{I(I)} = 0\text{ V}$	Full range	5	10		5	20		μA
Comparator reference voltage	$V_I = 4.5\text{ V to }6\text{ V}$	Full range	1.08	1.2	1.32	1.14	1.2	1.26	V
Comparator input bias current	$V_I = 6\text{ V}$	Full range	40	100		40	100		μA
Switch on-state voltage	$V_I = 4.5\text{ V}$	$I_O = 100\text{ mA}$	25°C	0.13	0.2	0.13	0.2		V
		$I_O = 500\text{ mA}$	Full range	0.85			1		
Switch off-state current	$V_I = 4.5\text{ V}, V_O = 30\text{ V}$	25°C	10	50		10	50		μA
		Full range		200			500		
Sense voltage, CUR LIM SENS	$V_I = 6\text{ V}$	25°C	0.45	1		0.45	1		V
Diode forward voltage	$I_O = 10\text{ mA}$	Full range	0.75	0.85		0.75	0.95		V
	$I_O = 100\text{ mA}$	Full range	0.9	1		0.9	1.1		
	$I_O = 500\text{ mA}$	Full range	1.33	1.55		1.33	1.75		
Diode reverse voltage	$I_O = 500\text{ }\mu\text{A}$	Full range				30			V
	$I_O = 200\text{ }\mu\text{A}$	Full range	30						
On-state supply current		25°C	11	14		11	14		mA
		Full range		15			16		
Off-state supply current		25°C	6	9		6	9		mA
		Full range		10			11		

† Full range is 0°C to 70°C for the TL497AC and –40°C to 85°C for the TL497AI.

‡ All typical values are at $T_A = 25^\circ\text{C}$.

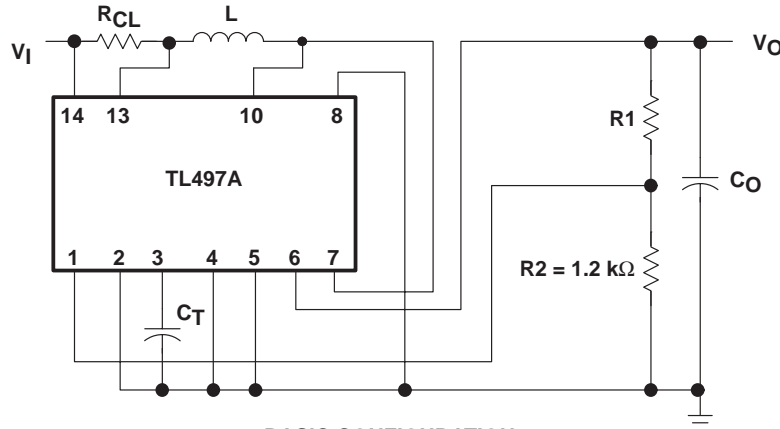
electrical characteristics over recommended operating conditions, $V_{CC} = 6\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TL497AY			UNIT
		MIN	TYP	MAX	
High-level input current, INHIBIT	$V_{I(I)} = 5\text{ V}$	0.8			mA
Low-level input current, INHIBIT	$V_{I(I)} = 0\text{ V}$	5			μA
Comparator reference voltage	$V_I = 4.5\text{ V to }6\text{ V}$	1.2			V
Comparator input bias current	$V_I = 6\text{ V}$	40			μA
Switch on-state voltage	$V_I = 4.5\text{ V}, I_O = 100\text{ mA}$	0.13			V
Switch off-state current	$V_I = 4.5\text{ V}, V_O = 30\text{ V}$	10			μA
Diode forward voltage	$I_O = 10\text{ mA}$	0.75			V
	$I_O = 100\text{ mA}$	0.9			
	$I_O = 500\text{ mA}$	1.33			
On-state supply current		11			mA
Off-state supply current		6			mA

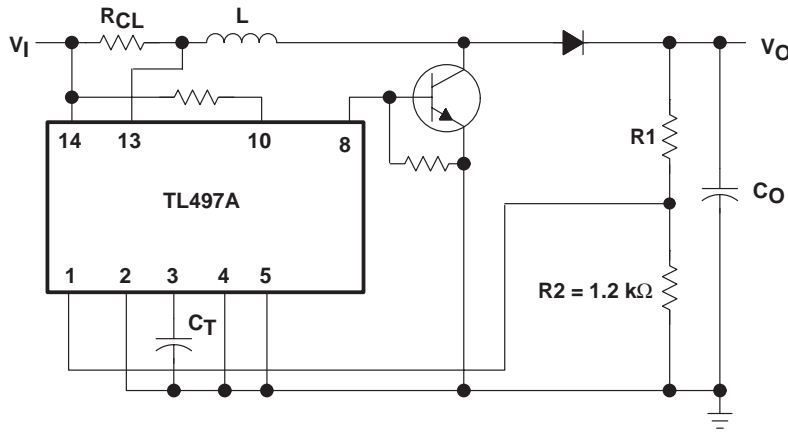


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APPLICATION INFORMATION



BASIC CONFIGURATION
(Peak Switching Current = $I_{(PK)} < 500 \text{ mA}$)



EXTENDED POWER CONFIGURATION
(using external transistor)

DESIGN EQUATIONS

- $I_{(PK)} = 2 I_O \max \left[\frac{V_O}{V_I} \right]$

- $L (\mu\text{H}) = \frac{V_I}{I_{(PK)}} t_{on} (\mu\text{s})$

Choose L (50 to 500 μH), calculate t_{on} (25 to 150 μs)

- $C_T (\text{pF}) \approx 12 t_{on} (\mu\text{s})$

- $R1 = (V_O - 1.2 \text{ V}) \text{ k}\Omega$

- $R_{CL} = \frac{0.5 \text{ V}}{I_{(PK)}}$

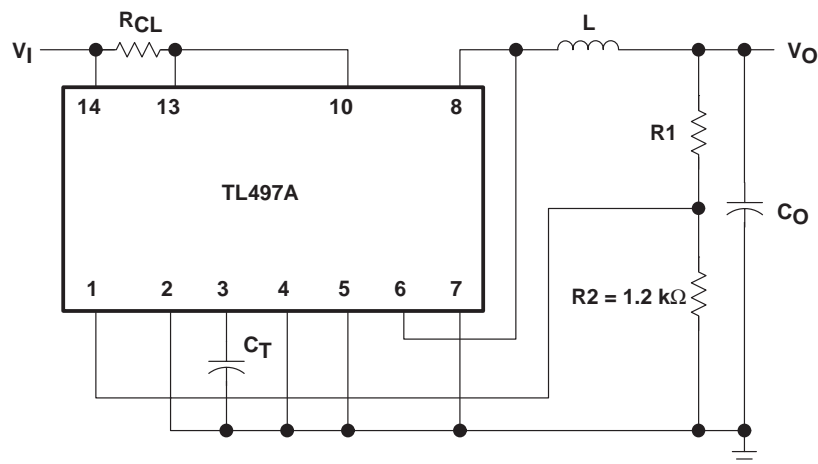
- $C_O (\mu\text{F}) \approx t_{on} (\mu\text{s}) \frac{\left[\frac{V_I}{V_O} I_{(PK)} + I_O \right]}{V_{\text{ripple (PK)}}}$

Figure 1. Positive Regulator, Step-Up Configurations

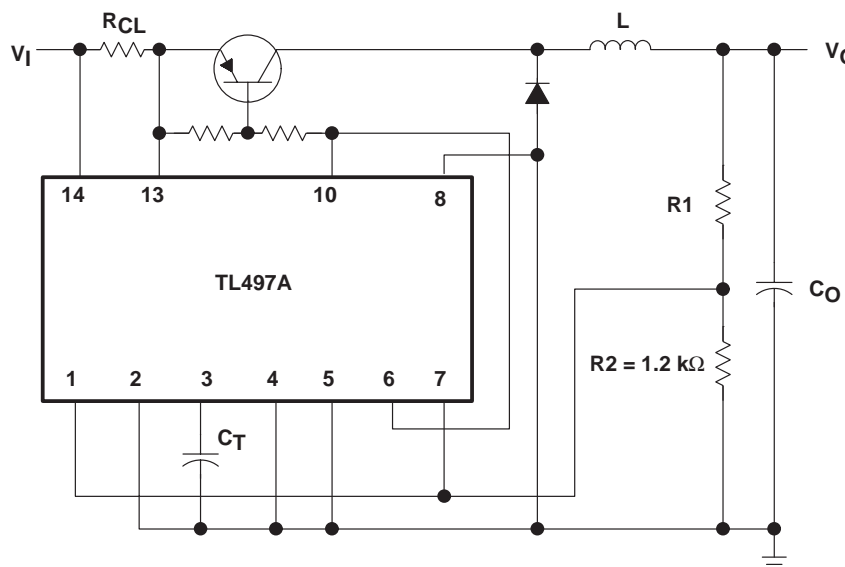
TL497A SWITCHING VOLTAGE REGULATORS

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APPLICATION INFORMATION



BASIC CONFIGURATION
(Peak Switching Current = $I_{(PK)} < 500 \text{ mA}$)



EXTENDED POWER CONFIGURATION
(using external transistor)

DESIGN EQUATIONS

- $I_{(PK)} = 2 I_O \text{ max}$

- $L (\mu\text{H}) = \frac{V_I - V_O}{I_{(PK)}} t_{on}(\mu\text{s})$

Choose L (50 to 500 μH), calculate t_{on} (10 to 150 μs)

- $C_T(\text{pF}) \approx 12 t_{on}(\mu\text{s})$

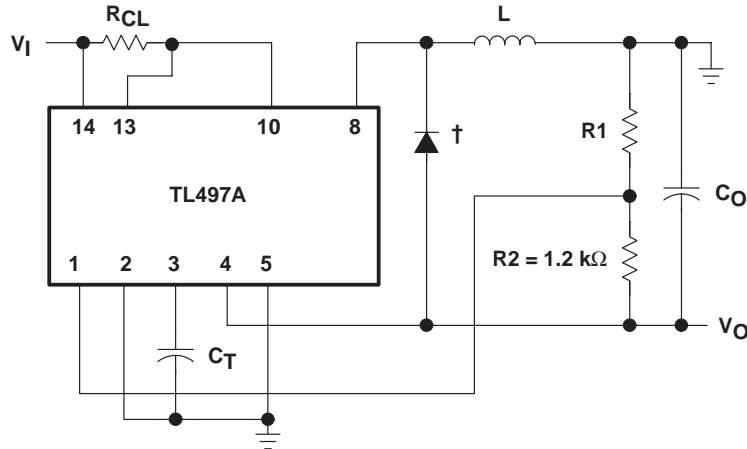
- $R1 = (V_O - 1.2 \text{ V}) \text{ k}\Omega$

- $R_{CL} = \frac{0.5 \text{ V}}{I_{(PK)}}$

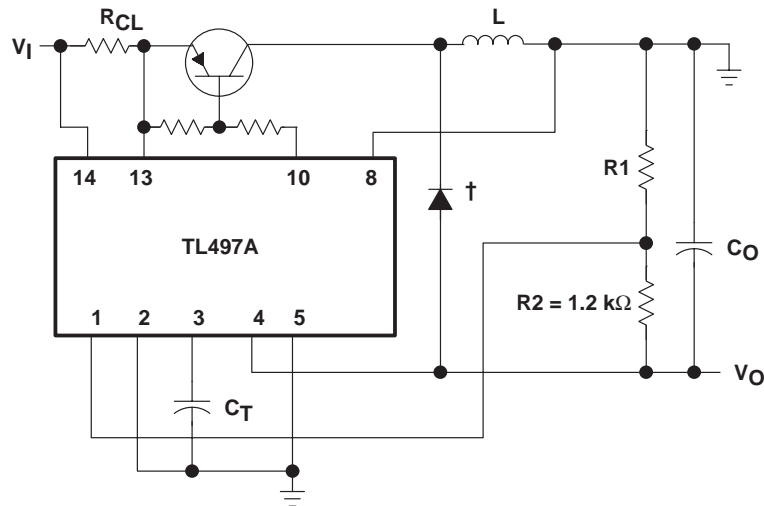
- $C_O (\mu\text{F}) \approx t_{on}(\mu\text{s}) \frac{\left[\frac{V_I - V_O}{V_O} I_{(PK)} + I_O \right]}{V_{\text{ripple}}(\text{PK})}$

Figure 2. Positive Regulator, Step-Down Configurations

APPLICATION INFORMATION



BASIC CONFIGURATION
(Peak Switching Current = $I_{(PK)} < 500$ mA)



EXTENDED POWER CONFIGURATION
(using external transistor)

DESIGN EQUATIONS

$$I_{(PK)} = 2 I_O \max \left[1 + \frac{|V_O|}{V_I} \right]$$

$$L (\mu H) = \frac{V_I}{I_{(PK)}} t_{on}(\mu s)$$

Choose L (50 to 500 μH), calculate t_{on} (10 to 150 μs)

$$C_T(pF) \approx 12 t_{on}(\mu s)$$

$$R1 = (|V_O| - 1.2 V) k\Omega$$

$$R_{CL} = \frac{0.5 V}{I_{(PK)}}$$

$$C_O (\mu F) \approx t_{on}(\mu s) \frac{\left[\frac{V_I}{|V_O|} I_{(PK)} + I_O \right]}{V_{ripple(PK)}}$$

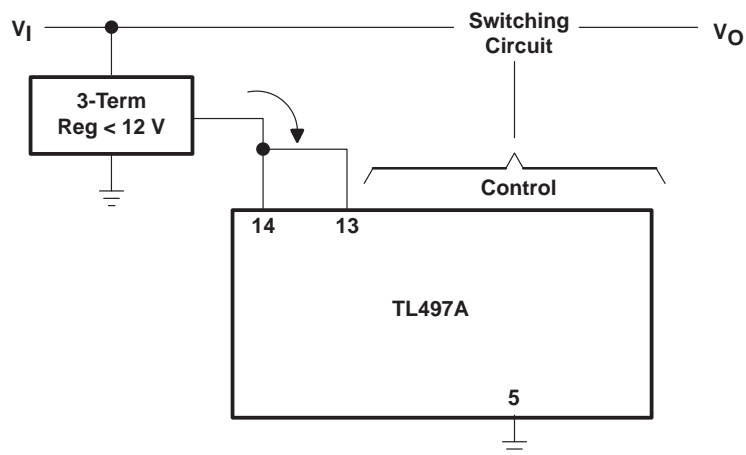
† Use external catch diode, e.g., 1N4001, when building an inverting supply with the TL497A.

Figure 3. Inverting Applications

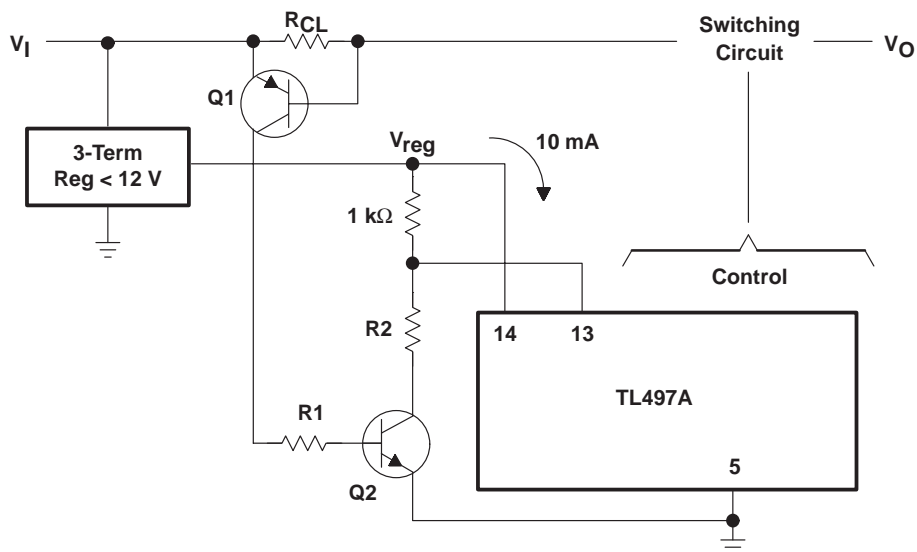
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APPLICATION INFORMATION



EXTENDED INPUT CONFIGURATION WITHOUT CURRENT LIMIT



DESIGN EQUATIONS

- $R_{CL} = \frac{V_{BE}(Q1)}{I_{limit} (PK)}$
- $R1 = \frac{V_I}{I_B(Q2)}$
- $R2 = (V_{reg} - 1) 10 \text{ k}\Omega$

CURRENT LIMIT FOR EXTENDED INPUT CONFIGURATION

Figure 4. Extended Input Voltage Range ($V_I > 12 \text{ V}$)

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